

SPEC SHEET (FOR REFERENCE)		SHEET No.		Rev.	Page.	
		G05053A		1	1 of 1	
TYPE:6PT2206P3T * *						
CHIP SIZE		0.4 * 0.4mm				
WAFER SIZE		6inch				
POSSIBLE DIE PER WAFER		95,200pcs				
Maximum Ratings (Ta=25°C)						
Characteristics	Symbol	Ratings	Unit			
Drain-source voltage	VDSS	-50	V			
Gate-source voltage	VGSS	±20	V			
WAFER PROBING SPEC (Ta=25°C)						
No	MODE	LIMIT				CONDITIONS
		MIN.	Typ	MAX.	UNIT	
1	IGSS			±10	uA	VGS=±20V VDS=0V
2	IDSS			-1	uA	VDS=-50V VGS=0V
3	BVDSS	-50			V	ID=-10uA
4	VTH	-0.8		-2	V	ID=-250uA VDS=VGS
5	RDS(on)1		2	4	Ω	ID=-100mA VGS=5.0V
6	RDS(on)2		1.8	3	Ω	ID=-130mA VGS=10.0V
<p>※ Built-in ZD between Gate and Source. (ESD1000V Protected)</p>						
NOTE:						